

## SWITCHMODE SERIES NPN POWER TRANSISTORS

... designed for use in high-voltage, high-speed, power switching in inductive circuit, they are particularly suited for 115 and 220 V switchmode applications such as switching regulator's, inverters, DC -DC converter, Motor Controls, Solenoid drive and Deflection circuits.

### FEATURES:

\*Collector-Emitter Sustaining Voltage-

$$V_{CE(sus)} = 400 \text{ V and } 300 \text{ V}$$

\* Collector-Emitter Saturation Voltage -

$$V_{CE(sat)} = 3.0 \text{ V (Max.) @ } I_C = 12 \text{ A, } I_B = 3.0 \text{ A}$$

\* Switching Time -  $t_f = 0.7 \text{ us (Max.) @ } I_C = 8.0 \text{ A}$

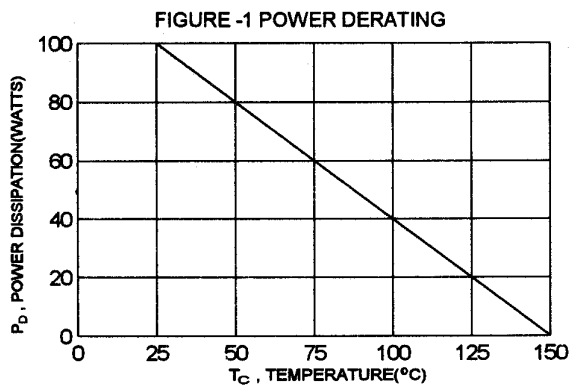
\* SOA and Switching Application Information.

### MAXIMUM RATINGS

Characteristic	Symbol	MJE13008	MJE13009	Unit
Collector-Emitter Voltage	$V_{CEO}$	300	400	V
Collector-Emitter Voltage	$V_{CEV}$	600	700	V
Emitter-Base Voltage	$V_{EBO}$	9		V
Collector Current - Continuous	$I_C$	12		A
- Peak	$I_{CM}$	24		
Base current	$I_B$	6		A
Total Power Dissipation @ $T_C = 25^\circ\text{C}$	$P_D$	100		W
Derate above $25^\circ\text{C}$		0.8		W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{STG}$	-65 to +150		$^\circ\text{C}$

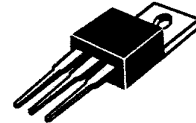
### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance Junction to Case	$R_{\theta jc}$	1.25	$^\circ\text{C/W}$

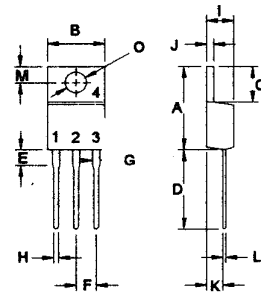


NPN  
MJE13008  
MJE13009

12 AMPERE  
POWER  
TRANSISTORS  
300-400 VOLTS  
100 WATTS



O-220



PIN 1.BASE  
2.COLLECTOR  
3.EMITTER  
4.COLLECTOR(CASE)

DIM	MILLIMETERS	
	MIN	MAX
A	14.68	15.31
B	9.78	10.42
C	5.01	6.52
D	13.06	14.62
E	3.57	4.07
F	2.42	3.66
G	1.12	1.36
H	0.72	0.96
I	4.22	4.98
J	1.14	1.38
K	2.20	2.97
L	0.33	0.55
M	2.48	2.98
O	3.70	3.90

**ELECTRICAL CHARACTERISTICS** (  $T_c = 25^\circ\text{C}$  unless otherwise noted )

Characteristic	Symbol	Min	Max	Unit
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**OFF CHARACTERISTICS**

Collector-Emitter Sustaining Voltage ( $I_C = 10\text{ mA}$ , $I_B = 0$ ) MJE13008 MJE13009	$V_{CEO(sus)}$	300 400		V
Collector Cutoff Current ( $V_{CEV} = \text{Rated Value}$ , $V_{BE(off)} = 1.5\text{ V}$ ) ( $V_{CEV} = \text{Rated Value}$ , $V_{BE(off)} = 1.5\text{ V}$ , $T_c = 100^\circ\text{C}$ )	$I_{CEV}$		1.0 5.0	mA
Emitter Cutoff Current ( $V_{EB} = 9.0\text{ V}$ , $I_C = 0$ )	$I_{EBO}$		1.0	mA

**ON CHARACTERISTICS (1)**

DC Current Gain ( $I_C = 5.0\text{ A}$ , $V_{CE} = 5.0\text{ V}$ ) ( $I_C = 8.0\text{ A}$ , $V_{CE} = 5.0\text{ V}$ )	hFE	8.0 6.0	40 30	
Collector-Emitter Saturation Voltage ( $I_C = 5.0\text{ A}$ , $I_B = 1.0\text{ A}$ ) ( $I_C = 8.0\text{ A}$ , $I_B = 1.6\text{ A}$ ) ( $I_C = 12\text{ A}$ , $I_B = 3.0\text{ A}$ )	$V_{CE(sat)}$		1.0 1.5 3.0	V
Base-Emitter Saturation Voltage ( $I_C = 5.0\text{ A}$ , $I_B = 1.0\text{ A}$ ) ( $I_C = 8.0\text{ A}$ , $I_B = 1.6\text{ A}$ )	$V_{BE(sat)}$		1.2 1.6	V

**DYNAMIC CHARACTERISTICS**

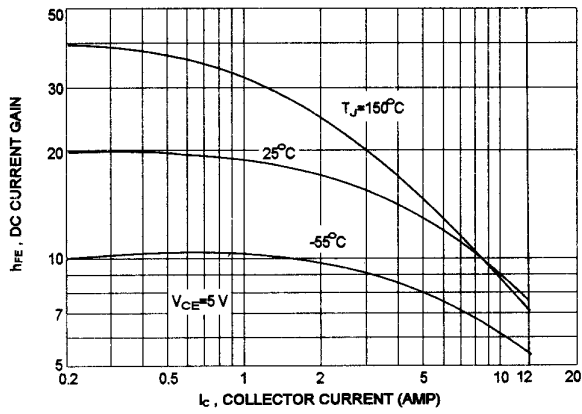
Current Gain - Bandwidth Product ( $I_C = 500\text{ mA}$ , $V_{CE} = 10\text{ V}$ , $f = 1.0\text{ MHz}$ )	$f_T$	4.0		MHz
Output Capacitance ( $V_{CB} = 10\text{ V}$ , $I_E = 0$ , $f = 0.1\text{ MHz}$ )	$C_{ob}$	180(typ)		pF

**SWITCHING CHARACTERISTICS**

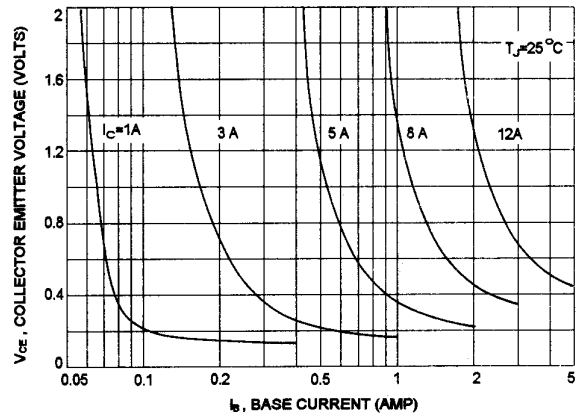
Delay Time	$V_{CC} = 125\text{ V}$ , $I_C = 8.0\text{ A}$ $I_{B1} = -I_{B2} = 1.6\text{ A}$ , $t_p = 25\text{ us}$ , Duty Cycle $\leq 1.0\%$	$t_d$	0.1	us
Rise Time		$t_r$	1.0	us
Storage Time		$t_s$	3.0	us
Fall Time		$t_f$	0.7	us

(1) Pulse Test: Pulse Width = 300 us, Duty Cycle  $\leq 2.0\%$

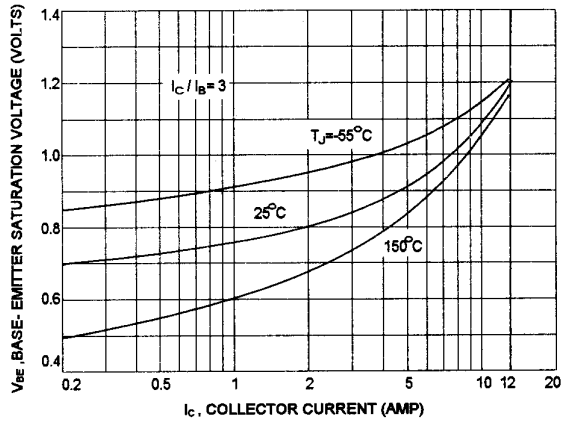
DC CURRENT GAIN



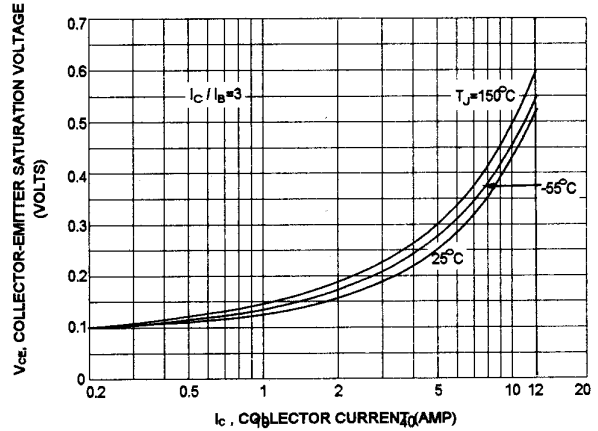
COLLECTOR SATURATION REGION



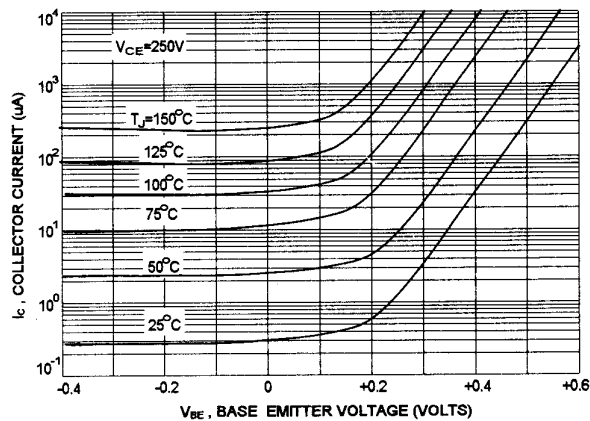
BASE-EMITTER SATURATION VOLTAGE



COLLECTOR-EMITTER SATURATION VOLTAGE



COLLECTOR CUT-OFF REGION



CAPACITANCE

